

## **Application**

Industrial use Biomedical

# **Property**

Wavelength  $\lambda = 405$  nm Output Power = 300 mW Package Type =  $\phi$  5.6mm

### Introduction

Egismos currently markets GaN based blue laser diodes 405nm, 450nm wavelengths range. The low operating current and high temperature of the laser diodes are achieved through using misoriented substrate and MQW (Strain compensated) active layer. Egismos laser diodes are highly rated in a broad range of applications including, but not limited to, laser pointers, green lasers, blue laser DVD, laser barcode scanners, diode laser equipments, medical instruments and aerospace applications.

## Laser Diode Key features

#### Absolute Maximum Rating at Tc=25℃

Items	Symbols	Values	Unit
Operating Current power	P <sub>o</sub>	300	mW
Reverse Voltage	$V_{R}$	2	V
Operating Temperature	$T_{case}$	0~+50	$^{\circ}\!\mathbb{C}$
Storage Temperature	$T_s$	-40~+85	$^{\circ}\!$



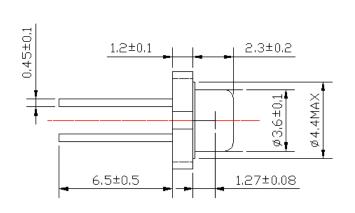


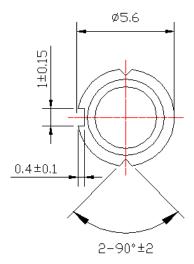
# 405nm BLUE Laser Diode

### Electrical and Optical Characteristics at Tc=25℃

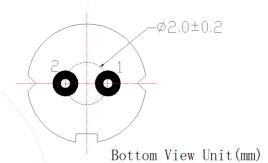
Item	Symbols	Min	Тур.	Max.	Unit	Condition
Threshold Current	$I_{th}$	-	140	200	mA	-
Operating Current	l <sub>op</sub>	250	325	400	mA	Po=300mW
Operating Voltage	$V_{op}$	-	4.5	5.5	V /	Po=300mW
Peak Wavelength	λр	395	405	415	nm	Po=300mW
Beam Divergence (FWHM)	$\theta_{/\!\!/}$	8	14	20	deg	Po=300mW
Beam Divergence (FWHM)	$ heta$ $\perp$	36	41	48	deg	Po=300mW

# **Package Drawing**





### **ELECTRICAL CONNECTION**





Specifications are subject to change without notice.







